MOSFET – Power, Single, N-Channel, SOT-23

20 V, 3.2 A

Features

- Leading Planar Technology for Low Gate Charge / Fast Switching
- 2.5 V Rated for Low Voltage Gate Drive
- SOT-23 Surface Mount for Small Footprint
- NVR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Load/Power Switch for Portables
- Load/Power Switch for Computing
- DC-DC Conversion

MAXIMUM RATINGS (T_J= 25°C unless otherwise stated)

| Parameter | | | Symbol | Value | Unit |
|---|------------------------------|-----------------------------|--------------------------------------|---------------|------|
| Drain-to-Source Voltage | | | V _{DSS} | 20 | V |
| Gate-to-Source Voltage | | | V _{GS} | ±12 | V |
| Continuous Drain | Steady T _A = 25°C | | I _D | 3.2 | Α |
| Current (Note 1) | State | State T _A = 85°C | | 2.4 | Α |
| Steady State Power Dissipation (Note 1) | Stea | dy State | P _D | 1.25 | W |
| Pulsed Drain Current | t _p = | : 10 μs | I _{DM} | 10.0 | Α |
| Operating Junction and Storage Temperature | | | T _J , T _{stg} | –55 to 150 | °C |
| Continuous Source Current (Body Diode) | | | Is | 1.6 | Α |
| Lead Temperature for Soldering Purposes (1/8" from case for 10 s) | | | TL | 260 | °C |

THERMAL RESISTANCE RATINGS

| Parameter | Symbol | Max | Unit |
|------------------------------|-----------------|-----|------|
| Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 100 | °C/W |
| Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 300 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).
- 2. Surface-mounted on FR4 board using the minimum recommended pad size.

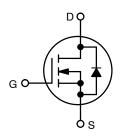


ON Semiconductor®

www.onsemi.com

| V _{(BR)DSS} | R _{DS(on)} Typ | I _D Max (Note 1) | |
|----------------------|-------------------------|--------------------------------|--|
| 20 V | 70 mΩ @ 4.5 V | 3.6 A | |
| | 88 mΩ @ 2.5 V | 3.1 A | |

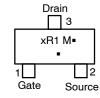
N-Channel



MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23 CASE 318 STYLE 21



TR1 = Device Code for NTR4501N VR1 = Device Code for NVR4501N

M = Date Code*■ Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping† |
|-------------|---------------------|--------------------|
| NTR4501NT1G | SOT-23 (Pb-Free) | 3000 / Tape & Reel |
| NVR4501NT1G | SOT-23 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Electrical Characteristics ($T_J = 25^{\circ}C$ unless otherwise specified)

| Symbol | Test Condition | | Min | Тур | Max | Units |
|--------------------------------------|--|---------------------------|---|---|---|---|
| • | | • | | • | | |
| V _{(BR)DSS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | | 20 | 24.5 | | V |
| V _{(BR)DSS} /T _J | | | | 22 | | mV/°C |
| I _{DSS} | V _{GS} = 0 V | T _J = 25°C | | | 1.5 | μΑ |
| | V _{DS} = 16 V | T _J = 85°C | | | 10 | μΑ |
| I _{GSS} | $V_{DS} = 0 V, V_{C}$ | _{SS} = ±12 V | | | ±100 | nA |
| | | | | | | |
| V _{GS(TH)} | V _{GS} = V _{DS} , I _E | ο = 250 μΑ | 0.65 | | 1.2 | V |
| V _{GS(TH)} /T _J | | | | -2.3 | | mV/°C |
| | V _{GS} = 4.5 V, | I _D = 3.6 A | | 70 | 80 | |
| R _{DS(on)} | V _{GS} = 2.5 V, I _D = 3.1 A | | | 88 | 105 | mΩ |
| 9FS | V _{DS} = 5.0 V, | I _D = 3.6 A | | 9 | | S |
| | | | | | | |
| C _{iss} | | | | 200 | | |
| C _{oss} | | | | 80 | | pF |
| C _{rss} | VDS = 10 V | | | 50 | | 1 |
| Q _{G(TOT)} | $V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V},$ $I_D = 3.6 \text{ A}$ | | | 2.4 | 6.0 | nC |
| Q_{GS} | | | | 0.5 | | |
| Q_{GD} | | | | 0.6 | | |
| | | | | | | |
| t _{d(on)} | | | | 6.5 | 13 | |
| t _r | V _{GS} = 4.5 V, V | _{'ns} = 10 V, | | 12 | 24 | ns |
| t _{d(off)} | $I_D = 3.6 A, R$ | $_{\rm G}$ = 6.0 Ω | | 12 | 24 | |
| t _f | | | | 3 | 6 | 1 |
| S | | | | | | |
| V_{SD} | V _{GS} = 0 V, I _S | _{SD} = 1.6 A | | 0.8 | 1.2 | V |
| t _{RR} | | | | 7.1 | | |
| t _a | V _{GS} = | 0 V, | | 5 | | ns |
| t _b | $d_{IS}/d_{t} = 100 \text{ A}/\mu\text{s},$ $I_{S} = 1.6 \text{ A}$ | | | 1.9 | | |
| | | | | | | |
| | Symbol V(BR)DSS V(BR)DSS/TJ IDSS V(BR)DSS/TJ IDSS V(BR)DSS/TJ V(BR)DSS/TJ V(BR)DSS/TJ V(BR)DSS/TJ V(BR)DSS V(BR)DSS/TJ V(BR)DS/TJ V(BR)DS/TJ V(BR)DS/TJ V(BR)DS/TJ V | V(BR)DSS | $ \begin{array}{ c c c } \hline \textbf{Symbol} & \textbf{Test Condition} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A} \\ \hline & V_{(BR)DSS}/T_{J} & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_{J} = 25^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_{J} = 85^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_{J} = 85^{\circ}\text{C} \\ \hline & V_{GS}(TH) & V_{GS} = V_{DS}, I_{D} = 250 \mu\text{A} \\ \hline & V_{GS}(TH)/T_{J} & \\ \hline & V_{GS}(TH)/T_{J} & \\ \hline & V_{GS} = 4.5 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 2.5 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 2.5 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{DS} = 5.0 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz}, \\ \hline & V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_{D} = 3.6 \text{ A} & \\ \hline & V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_{D} = 3.6 \text{ A}, R_{G} = 6.0 \Omega \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} = 1.0 \text{ A} / \mu_{S}, \\ \hline & V_{GS} = 0 \text{ V}, I_{D} $ | $ \begin{array}{ c c c c } \hline \textbf{Symbol} & \textbf{Test Condition} & \textbf{Min} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A} & 20 \\ \hline & V_{(BR)DSS}/T_J & & & & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_J = 25^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_J = 85^{\circ}\text{C} \\ \hline & I_{GSS} & V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V} \\ \hline & V_{GS(TH)} & V_{GS} = V_{DS}, I_D = 250 \mu\text{A} & 0.65 \\ \hline & V_{GS(TH)}/T_J & & & \\ \hline & V_{GS} = 4.5 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & V_{GS} = 2.5 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & V_{DS} = 5.0 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & V_{DS} = 5.0 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & C_{ISS} & V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz}, \\ \hline & C_{CRS} & V_{GS} = 0 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_D = 3.6 \text{ A} \\ \hline & V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_D = 3.6 \text{ A}, R_G = 6.0 \Omega \\ \hline & V_{SD} & V_{GS} = 0 \text{ V}, I_{SD} = 1.6 \text{ A} \\ \hline & t_{RR} & V_{GS} = 0 \text{ V}, \\ \hline & I_D / $ | $ \begin{array}{ c c c c c } \hline \textbf{Symbol} & \textbf{Test Condition} & \textbf{Min} & \textbf{Typ} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A} & 20 & 24.5 \\ \hline & V_{(BR)DSS}/T_J & & 22 & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_J = 25^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_J = 85^{\circ}\text{C} & \\ \hline & I_{GSS} & V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V} \\ \hline \hline & V_{GS(TH)} & V_{GS} = V_{DS}, I_D = 250 \mu\text{A} & 0.65 & \\ \hline & V_{GS(TH)}/T_J & & -2.3 & \\ \hline & V_{GS(TH)}/T_J & & -2.3 & \\ \hline & V_{GS}(TH)/T_J & & -2.3 & \\ \hline & V_{GS} = 4.5 \text{ V}, I_D = 3.6 \text{ A} & 70 & \\ \hline & V_{GS} = 2.5 \text{ V}, I_D = 3.6 \text{ A} & 9 & \\ \hline & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & $ | $ \begin{array}{ c c c c c c } \hline \textbf{Symbol} & \textbf{Test Condition} & \textbf{Min} & \textbf{Typ} & \textbf{Max} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \ \mu\text{A} & 20 & 24.5 \\ \hline & V_{(BR)DSS}/T_J & 22 & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_J = 25^{\circ}\text{C} & 1.5 \\ \hline & V_{DS} = 16 \text{ V} & T_J = 85^{\circ}\text{C} & 10 \\ \hline & I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 12 \text{ V} & \pm 100 \\ \hline & V_{GS(TH)} & V_{GS} = V_{DS}, I_D = 250 \ \mu\text{A} & 0.65 & 1.2 \\ \hline & V_{GS(TH)}/T_J & -2.3 & \\ \hline & V_{GS(TH)}/T_J & -2.3 & \\ \hline & V_{GS} = 4.5 \text{ V, } I_D = 3.6 \text{ A} & 70 & 80 \\ \hline & V_{GS} = 2.5 \text{ V, } I_D = 3.6 \text{ A} & 9 & \\ \hline & V_{GS} = 2.5 \text{ V, } I_D = 3.6 \text{ A} & 9 & \\ \hline & V_{GS} = 5.0 \text{ V, } I_D = 3.6 \text{ A} & 9 & \\ \hline & V_{GS} = 0 \text{ V, } f = 1.0 \text{ MHz,} & 200 \\ \hline & V_{GS} = 0 \text{ V, } f = 1.0 \text{ MHz,} & 80 \\ \hline & V_{GS} = 4.5 \text{ V, } V_{DS} = 10 \text{ V,} & 2.4 & 6.0 \\ \hline & V_{GS} = 4.5 \text{ V, } V_{DS} = 10 \text{ V,} & 0.5 & \\ \hline & I_D = 3.6 \text{ A, } R_G = 6.0 \ \Omega & 12 & 24 \\ \hline & I_T & V_{GS} = 4.5 \text{ V, } V_{DS} = 10 \text{ V,} & 12 & 24 \\ \hline & I_T & 0.5 & 0.6 \\ \hline & V_{SD} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & V_{SD} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & I_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & I_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_{C} = 100 \text{ A/µs,} & 5 & \\ \hline & I_{S}/I_$ |

Pulse Test: Pulse width ≤ 300 μs, duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

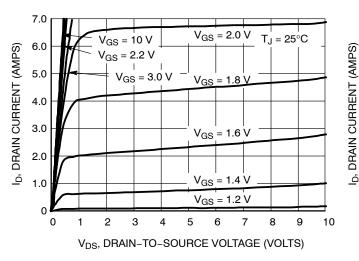
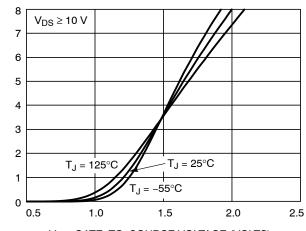


Figure 1. On-Region Characteristics



V_{GS}, GATE-TO-SOURCE VOLTAGE (VOLTS)

Figure 2. Transfer Characteristics

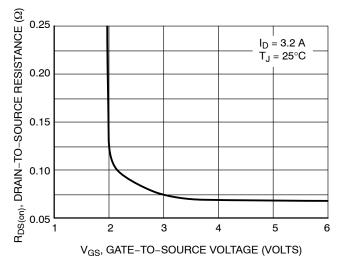


Figure 3. On-Resistance versus Gate-to-Source Voltage

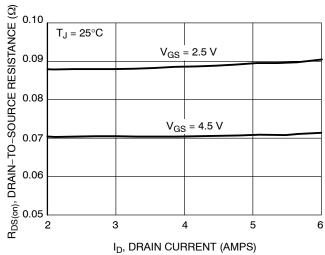


Figure 4. On-Resistance versus Drain Current and Gate Voltage

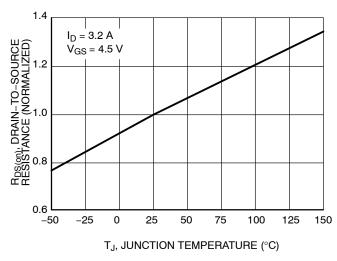


Figure 5. On–Resistance Variation with Temperature

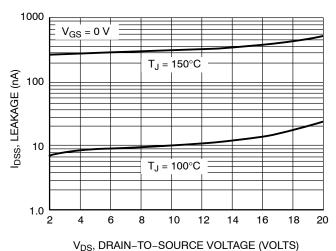


Figure 6. Drain-to-Source Leakage Current versus Voltage

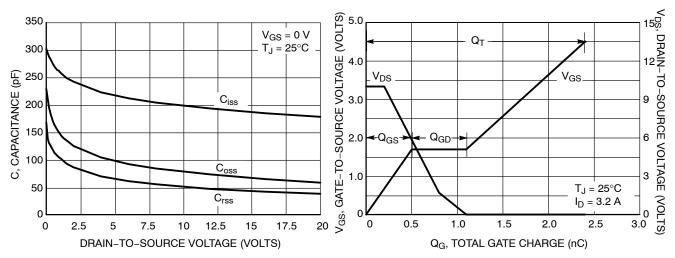


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

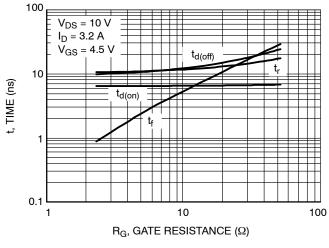


Figure 9. Resistive Switching Time Variation versus Gate Resistance

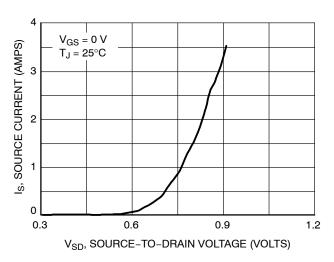


Figure 10. Diode Forward Voltage versus
Current

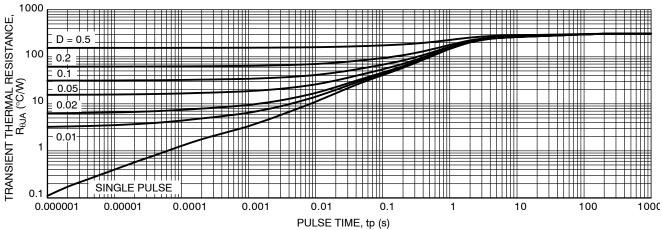


Figure 11. Thermal Response





SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023









NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIM | IETERS | | | INCHES | |
|-----|--------|--------|------|-------|--------|-------|
| DIM | MIN. | N□M. | MAX. | MIN. | N□M. | MAX. |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| С | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| Ε | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | 0* | | 10° | 0* | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

STYLES ON PAGE 2

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|------------------|-----------------|---|-------------|--|
| DESCRIPTION: | SOT-23 (TO-236) | | PAGE 1 OF 2 | |

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | 1 | |
|---|---|---|---|---|---|
| STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE | STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE | STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE | STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 13: PIN 1. SOURCE 2. DRAIN 3. GATE | STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE |
| STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE | STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE | STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE | STYLE 18: PIN 1. NO CONNECTION 2. CATHODE 3. ANODE | STYLE 19: N PIN 1. CATHODE 2. ANODE 3. CATHODE-ANODE | STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE |
| STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN | STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT | STYLE 23: PIN 1. ANODE 2. ANODE 3. CATHODE | STYLE 24: PIN 1. GATE 2. DRAIN 3. SOURCE | STYLE 25: PIN 1. ANODE 2. CATHODE 3. GATE | STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | | | | |

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